

APPROVAL SHEET

MULTILAYER CERAMIC CAPACITORS

Open-Mode Series (50V to 630V)

0805 to 1812 Sizes

X7R Dielectric

Halogen Free & RoHS Compliance

*Contents in this sheet are subject to change without prior notice.

Multilayer Ceramic Capacitors



Approval Sheet

1. INTRODUCTION

WTC open-mode series MLCC is designed by a special internal electrode pattern, which can reduce voltage concentrations by distributing voltage gradients throughout the entire capacitor. This special design also affords open-mode pattern to prevent circuit leakage when focused to failure in a board flex situation.

2. FEATURES

- a. High voltage in a given case size.
- b. Circuit open during product cracking.
- c. High stability and reliability.

3. APPLICATIONS

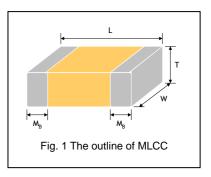
- a. High current applications.
- b. Power supply and related industries
- c. The other mechanical stress concerned products.

4. HOW TO ORDER

<u>OP</u>	<u>31</u>	<u>B</u>	<u>102</u>	<u>K</u>	<u>201</u>	<u>C</u>	I
<u>Series</u>	Size	Dielectric	Capacitance	Tolerance	Rated voltage	Termination	<u>Packaging</u>
OP =Open-mode	21 =0805 (2012)	B=X7R	Two significant	K=±10%	Two significant	C =Cu/Ni/Sn	T=7" reeled
	31 =1206 (3216)	1.47	digits followed	M=±20%	digits followed by		G=13" reeled
	32 =1210 (3225)	I I X	by no. of zeros.	目於	no. of zeros. And		
	43 =1812 (4532)	17717	And R is in	<	R is in place of		
			place of		decimal point.		
		相對	decimal point.	- ^			
				A	500 =50 VDC		
		8	eg.ssive syste	EM ALLIANC	101 =100 VDC		
		COPURACI	102=10x10 ²		201=200 VDC		
		10000000000000000000000000000000000000	=1000pF		251 =250 VDC		
					501 =500 VDC		
		Ma	Pol	9700	631 =630 VDC		

5. EXTERNAL DIMENSIONS

Size Inch (mm)	L (mm)	W (mm)	T (mm)/Symbol		Remark	M _B (mm)	
0805 (2012)	2.00±0.15	1.25±0.10	0.80±0.10	В		0.40±0.20	
0003 (2012)	2.00±0.13	1.25±0.10	1.25±0.10	D	#	0.40±0.20	
			0.80±0.10	В			
4000 (2040)	3.20±0.15	1.60±0.15	0.95±0.10	С		0.50.0.00	
1206 (3216)			1.25±0.10	D	#	0.50±0.20	
	3.20±0.20	1.60±0.20	1.60±0.20	G	#		
	0.00.000	0.50.000	0.95±0.10	С	#		
1010 (2025)	3.20±0.30	2.50±0.20	1.25±0.10	D	#	0.50.0.25	
1210 (3225)	2 20 . 0 40	2.50±0.30	1.60±0.20	G	#	0.50±0.25	
	3.20±0.40		2.50±0.30	М	#		
1812 (4532)	4.50+0.5/-0.3	3.20±0.30	1.25±0.10	D	#	0.60+0.25	
1012 (4552)	4.50+0.5/-0.5	3.20±0.30	2.00±0.20	K	#	0.60±0.25	



6. GENERAL ELECTRICAL DATA

Dielectric	X7R K Ta
Size	0805, 1206, 1210, 1812
Capacitance*	100pF to 1µF
Capacitance tolerance**	K (±10%), M (±20%)
Rated voltage (WVDC)	50V, 100V, 200V, 250V, 500V, 630V
	50V,100V: ≥2.5 x WVDC
Dielectric strength	200V and 250V: ≥2 x WVDC
	500V,630V: ≥1.5 x WVDC
Operating temperature	-55 to +125℃
Capacitance characteristic	±15%
Termination	Ni/Sn (lead-free termination)

^{*} Measured at 25°C ambient temperature and 30~70% related humidity. Apply 1.0±0.2Vrms, 1.0kHz±10%.

[#] Reflow soldering only is recommended.

^{**} Preconditioning for Class II MLCC: Perform a heat treatment at 150±10°C for 1 hour, then leave in a mbient condition for 24±2 hours before measurement.

Multilayer Ceramic Capacitors

7. CAPACITANCE RANGE

Г	IELECTRIC											X7R										
_	SIZE			0805					12	06		ATT			1210					1812		
RAT	ED VOLTAGE	100	200	250	500	630	50	100	_	250	500	630	100		_		630	100	200	250		630
	100pF (101)	В	В	В	В	В					000	000				000	000			_00	000	000
	120pF (121)	В	 B	В	В	В																
-	150pF (151)	В	В	В	В	В	В	В	D	D	D	D										
-	180pF (181)	В	В	В	В	В	В	В	D	D	D	D										
	220pF (221)	В	В	В	В	В	В	В	D	D	D	D										
•	270pF (271)	В	В	В	В	В	В	В	D	D	D	D										
	330pF (331)	В	В	В	В	В	В	В	D	D	D	D										
	390pF (391)	В	В	В	В	В	В	В	D	D	D	D										
	470pF (471)	В	В	В	В	В	В	В	D	D	D	D										
	560pF (561)	В	В	В	В	В	В	В	D	D	D	D										
	680pF (681)	В	В	В	В	В	В	В	D	D	D	D										
	820pF (821)	В	В	В	В	В	В	В	D	D	D	D										
	1,000pF (102)	В	В	В	В	В	В	В	D	D	D	D	С	С	С	D	D	D	D	D	D	D
	1,200pF (122)	В	В	В	В	В	В	В	D	D	D	D	С	С	С	D	О	О	D	D	D	О
	1,500pF (152)	В	В	В	В	В	В	В	D	D	D	D	С	С	С	D	D	D	D	D	D	D
	1,800pF (182)	В	В	В	В	В	В	В	D	D	D	D	С	С	С	D	D	D	D	D	D	D
	2,200pF (222)	В	В	В	В	В	В	В	D	D	D	D	С	С	С	D	D	D	D	D	D	D
	2,700pF (272)	В	В	В	В	В	В	В	D,	D	D	D	С	С	С	D	D	D	D	D	D	D
	3,300pF (332)	В	В	В	В	В	В	В	D	D	D	D	С	С	С	D	D	D	D	D	D	D
	3,900pF (392)	В	В	В			В	В	D	D	D	D.	C	С	С	D	D	D	D	D	D	D
	4,700pF (472)	В	В	В		/X	В	В	D	-D	D	D	e	С	С	D	D	D	D	D	D	D
	5,600pF (562)	В	D	D	/	XIV.	В	В	D	D	D	D	C/	C	С	D	D	D	D	D	D	D
8	6,800pF (682)	В	D	D	/7	79[7]	В	В	D	D	D	D	C	Ç,	С	D	D	D	D	D	D	D
tau	8,200pF (822)	В	D	D		<u> </u>	В	В	D	D	D	D	C	С	С	D	D	D	D	D	D	D
aci	0.010µF (103)	В	D	D		<u> </u>	В	В	D	D	D	D	C	С	С	D	D	D	D	D	D	D
Capacitance	0.012µF (123)	В	D	D			В	В	D	D	D	D	С	С	С	D	D	D	D	D	D	D
Ŭ,	0.015µF (153)	В	D	D	15	5	В	ASB:I	√∈D= \	rs Đ∈⊪	_AD∟:	:ADce	С	C	-C	D	D	D	D	D	D	D
	0.018µF (183)	В	D	D	15		В	В	D	D	D	D	С	C	C	D	D	D	D	D	D	D
-	0.022µF (223)	B D	D	D	1		B B	В	D D	D D	G	G	C	C	C	D D						
	0.027µF (273)						В	В	G	G	G	G	С	C	С	G	G	D	D	D	D	D
	0.033µF (333)	D D			-		В	В	G	G	G	G	C	C	С	G	G	D	D	D	D	D
-	0.039µF (393) 0.047µF (473)	D				13	В	В	G	G	40		C	D	D	G	G	D	D	D	D	D
	0.047μF (473) 0.056μF (563)						В	В)/G/	/ G	1000	10/4	С	D	D	G	G	D	D	D	K	K
	0.050μF (503)						В	В	G	G	YURP	110	С	G	G	G	G	D	D	D	K	K
	0.082μF (823)						D	D	G	G			С	G	G			D	D	D	K	K
	0.10µF (104)						D	D	G	G			С	G	G			D	D	D	K	K
	0.12µF (124)						D	D					C	G	G			D	D	D	_	
	0.15µF (154)						D	G					D	М	М			D	K	K		
	0.18µF (184)						D	G					D	М	М			D	K	K		
	0.22µF (224)						D	G					D	М	М			D	K	K		
	0.27µF (274)						D						G					D	K	K		
	0.33µF (334)						D						G					D	K	K		
	0.39µF (394)						D						М					D	K	K		
	0.47µF (474)						D						М					K	K	K		
	0.56µF (564)												М					K				
	0.68µF (684)																	K				
	0.82μF (824)																	K				
	1.0µF (105)																	K				

The letter in cell is expressed the symbol of product thickness.



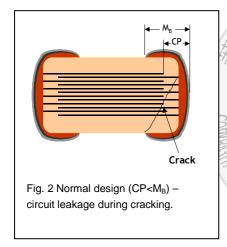
Approval Sheet

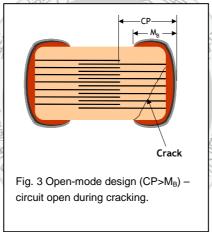
8. PACKAGING DIMENSION AND QUANTITY

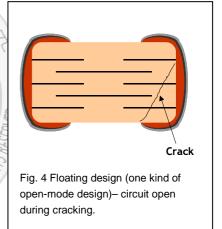
Cina	This language (many) (C	a made a l	Pape	r tape	Plasti	c tape
Size	Thickness (mm)/Symbol -		7" reel	13" reel	7" reel	13" reel
0805	0.80±0.10	В	4k	15k	=	-
0605	1.25±0.10	D	-	-	3k	10k
	0.80±0.10	В	4k	15k	-	-
4000	0.95±0.10	С	-	-	3k	10k
1206	1.25±0.10	D	-	-	3k	10k
	1.60±0.20	G	-	-	2k	10k
	0.95±0.10	С	-	-	3k	10k
4040	1.25±0.10	D	-	-	3k	10k
1210	1.60±0.20	G	-	-	2k	-
	2.50±0.30	М	-	-	1k	6k
1812	1.25±0.10	D	-	-	1k	5k
1012	2.00±0.20	K	-	-	1k	-

Unit: pieces

9. INNER CONSTRUCTION OF OPEN-MODE DESIGN









10. RELIABILITY TEST CONDITIONS AND REQUIREMENTS

No.	Item	Test Condition	Requirements
1.	Visual and		* No remarkable defect.
	Mechanical		* Dimensions to conform to individual specification sheet.
2.	Capacitance	1.0±0.2Vrms, 1kHz±10%	* Shall not exceed the limits given in the detailed spec.
3.	Q/ D.F.	*Before initial measurement (Class II only): To apply de-aging	* D.F. ≤2.5%
	(Dissipation	at 150°C for 1hr then set for 24±2 hrs at room temp.	* D.F. ≤3% : 50V / 1206≧ 0.47µF
	Factor)		·
4.	Dielectric	* To apply voltage:	* No evidence of damage or flash over during test.
	Strength	50V, 100V ≥2.5 times VDC	
		200V~300V ≥2 times VDC	
		500V~630V ≥1.5 times VDC	
		* Duration: 1 to 5 sec.	
		* Charge & discharge current less than 50mA.	
5.	Insulation	50V, 100V, To apply rated voltage for max. 120 sec.	≥10GΩ or RxC≥100Ω-F whichever is smaller.
	Resistance	≥200V, To apply rated voltage for 60 sec.	X7R=100V: RxC≥100Ω-F
6.	T	Mills or all strictles d	William AFO/
0.	Temperature Coefficient	With no electrical load.	Within ±15%.
	Coemcient	Operating temperature: -55~125°C at 25°C Before initial measurement (Class II only): To apply de-aging	\$ \(\tau_{\text{\ti}\}\text{\ti}\xitint{\texi\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\tetx}\text{\tetx}\\ \text{\text{\text{\text{\text{\text{\text{\text{\text{\texi}\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\texi}}\\ \text{\ti}\text{\text{\text{\text{\text{\text{\text{\text{\text{\te
		at 150°C for 1hr then set for 24±2 hrs at room temp.	
7.	Adhesive	* Pressurizing force :	* No remarkable damage or removal of the terminations.
	Strength of	5N (≤0603) and 10N (>0603)	The formal data and a first of the formal and the
	Termination	* Test time: 10±1 sec.	$\nabla ($
8.	Vibration	* Vibration frequency: 10~55 Hz/min.	* No remarkable damage.
	Resistance	* Total amplitude: 1.5mm	* Cap change and Q/D.F.: To meet initial spec.
		* Test time: 6 hrs. (Two hrs each in three mutually	IANCE C
		perpendicular directions.)	2 8
		*Before initial measurement (Class II only): To apply de-aging	[S S
		at 150℃ for 1hr then set for 24±2 hrs at room temp.	
		*Cap./DF(Q) Measurement to be made after de-aging at 150℃	013.60
_		for 1hr then set for 24±2 hrs at room temp.	2011
9.	Solderability	* Solder temperature: 235±5°C	95% min. coverage of all metalized area.
10	D	* Dipping time: 2±0.5 sec.	* No
10.	Bending Test	* The middle part of substrate shall be pressurized by means of the pressurizing rod at a rate of about 1 mm per second until	- I
			I
		the deflection becomes 1 mm and then the pressure shall be maintained for 5±1 sec.	(This capacitance change means the change of capacitance under specified flexure of substrate from the capacitance measured before
			the test.)
		at 150°C for 1hr then set for 24±2 hrs at room temp.	une test.)
		* Measurement to be made after keeping at room temp. for	
		24±2 hrs.	
11.	Resistance to	* Solder temperature: 260±5℃	* No remarkable damage.
	Soldering Heat	* Dipping time: 10±1 sec	* Cap change: X7R: within ±7.5%
		* Preheating: 120 to 150℃ for 1 minute before imme rse the	* Q/D.F., I.R. and dielectric strength: To meet initial requirements.
		capacitor in a eutectic solder.	* 25% max. leaching on each edge.
		*Before initial measurement (Class II only): To apply de-aging	
		at 150°C for 1hr then set for 24±2 hrs at room temp.	
		*Cap. / DF(Q) / I.R. Measurement to be made after de-aging at	
		150℃ for 1hr then set for 24±2 hrs at room temp.	



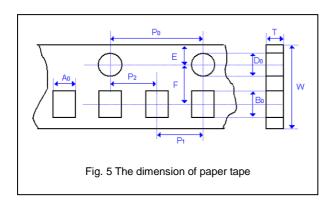
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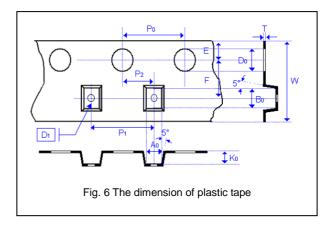
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No.	Item		Test Condition		Requirements				
12.	Temperature	* Conduc	t the five cycles according to the ter	mperatures and	No remarkable damage.				
	Cycle	time.			*Cap change:within ±7.5%				
		Step	Step Temp. (℃)		* Q/D.F., I.R. and dielectric strength: To meet initial requirements.				
		1	Min. operating temp. +0/-3	30±3					
		2	Room temp.	2~3					
		3	Max. operating temp. +3/-0	30±3					
		4	Room temp.	2~3					
		*Before ir	nitial measurement (Class II only): T	o apply de-aging					
		at 150℃ f	for 1hr then set for 24±2 hrs at room	n temp.					
		* Cap. / D	OF(Q) / I.R. Measurement to be made	le after de-aging					
		at 150℃ f	for 1hr then set for 24±2 hrs at room	n temp.					
13.	Humidity	* Test ten	np.: 40±2℃		* No remarkable damage.				
	(Damp Heat)	* Humidit	y: 90~95% RH		* Cap change: within ±12.5%				
	Steady State	* Test tim	e: 500+24/-0hrs.		* Q/D.F. value:				
		*Before in	nitial measurement (Class II only):	To apply de-aging	D.F. ≤3.0%				
		at 150℃ f	for 1hr then set for 24±2 hrs at room	n temp.	D.F. ≤6% : 50V / 1206≧ 0.47µF				
		* Cap. / D	PF(Q) / I.R. Measurement to be made	le after de-aging	* I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.				
		at 150℃ t	for 1hr then set for 24±2 hrs at room	n temp.	X7R=100V: RxC≥10Ω-F				
14.	Humidity	* Test ten	np.: 40±2℃		* No remarkable damage.				
	(Damp Heat)	* Humidit	y: 90~95%RH	右	* Cap change: within ±12.5%				
	Load	* Test tim	e: 500+24/-0 hrs.	/H	* Q/D.F. value:				
		* To apply	voltage: rated voltage (Max. 500)	此阳仏 ·	D.F.≤3,0%				
		*Before in	nitial measurement (Class II only):	To apply de-aging	g D.F. ≤6% : 50V / 1206 ≥ 0.47μF				
		at 150℃ f	for 1hr then set for 24±2 hrs at room	n temp.	* I.R.: ≥500MΩ or RxC≥25Ω-F whichever is smaller.				
		* Cap. / D	DF(Q) / I.R. Measurement to be made	de after de-aging	X7R=100V: RxC≥5Ω-F				
		at 150℃	for 1hr then set for 24±2 hrs at room	m temp.					
15.	High	* Test ten	np.: X7R: 125±3℃		* No remarkable damage.				
	Temperature	* To apply	voltage: PASSI	VE SYSTEM AL	* Cap change: within ±12.5%				
	Load	(1) V<500	OV: 200% of rated voltage.		* Q/D.F. value:				
	(Endurance)	(2) 500V	-630V: 150% of rated voltage.		D.F. ≤3.0%				
		* Test tim	e: 1000+24/-0 hrs.		D.F. ≤6% : 50V / 1206 ≧ 0.47µF				
		*Before ir	nitial measurement (Class II only): T	o apply de-aging	* I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.				
		at 150℃ f	for 1hr then set for 24±2 hrs at room	temp.	X7R=100V: RxC≥10Ω-F				
		* Cap. / D	F(Q) / I.R. Measurement to be made	le after de-aging	TION. C.				
		at 150℃ i	for 1hr then set for 24±2 hrs at room	temp! CORPOR					

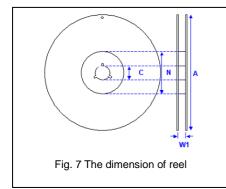
APPENDIXES

■ Tape & reel dimensions



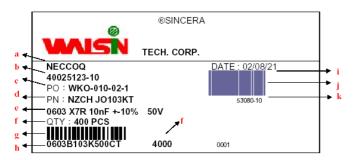


Size	08	05		1206		12	:10	1812
Thickness	В	C, D, I	В	C, D	G	C, D	G	D, K, M
A ₀	1.50 +/-0.20	< 1.80	1.90 +/-0.50	< 2.00	<2.30	< 3.05	< 3.05	< 3.20
B ₀	2.30 +/-0.20	< 2.70	3.50 +/-0.50	3.70	< 4.00	< 3.80	< 3.80	<4.00
Т	≦1.20	0.23 +/-0.1	≨1.20	0.23 +/-0.1	0.23 +/-0.1	0.23 +/-0.1	0.23 +/-0.1	0.23 +/-0.1
K ₀	-	< 2.50		< 2.50	< 2.50	< 1.50	< 2.50	< 3.20
w	8.00	8.00	8.00	8.00	8.00	8.00	8.00	8.00
	+/-0.30	+/-0.30	+/-0.30	+/-0.30	+/-0.30	+/-0.30	+/-0.30	+/-0.30
P ₀	4.00	4.00	4.00	4.00	4.00	4.00	4.00	4.00
	+/-0.10	+/-0.10	+/-0.10	/e +/-0.10 ALI	TAN+/-0.10	+/-0.10	+/-0.10	+/-0.10
10xP₀	40.00	40.00	40.00	40.00	40.00	40.00	40.00	40.00
	+/-0.20	+/-0.20	+/-0.20	+/-0.20	+/-0.20	+/-0.20	+/-0.20	+/-0.20
P ₁	4.00	4.00	4.00	4.00	4.00	4.00	4.00	4.00
	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10
P ₂	2.00	2.00	2.00	2.00	2.00	2.00	2.00	2.00
	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05
D ₀	1.50	1.50	1.50	1.50	1.50	1.50	1.50	1.50
	+0.1/-0	+0.1/-0	+0.1/-0	//_+0.1/-0	+0.1/-0	+0.1/-0	+0.1/-0	+0.1/-0
D ₁	-	1.00 +/-0.10	-	1.00 +/-0.10	1.00 +/-0.10	1.00 +/-0.10	1.00 +/-0.10	1.00 +/-0.10
E	1.75	1.75	1.75	1.75	1.75	1.75	1.75	1.75
	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10
F	3.50	3.50	3.50	3.50	3.50	3.50	3.50	3.50
	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05



Size	06	1808, 1812		
Reel size	7"	10"	13"	7"
С	13.0+0.5/-0.2	13.0+0.5/-0.2	13.0+0.5/-0.2	13.0+0.5/-0.2
W ₁	8.4+1.5/-0	8.4+1.5/-0	8.4+1.5/-0	12.4+2.0/-0
Α	178.0±1.0	250.0±1.0	330.0±1.0	178.0±1.0
N	60.0+1.0/-0	100.0±1.0	100±1.0	60.0+1.0/-0

Example of customer label

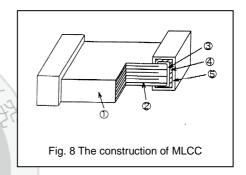


^{*}Customized label is available upon request

- a. Customer name
- b. WTC order series and item number
- c. Customer P/O
- d. Customer P/N
- e. Description of product
- f. Quantity
- g. Bar code including quantity & WTC P/N or customer
- h. WTC P/N
- i. Shipping date
- j. Order bar code including series and item numbers
- k. Serial number of label

Constructions

No.	Nan	ne	X7R
①	Ceramic r	material	BaTiO₃ based
2	Inner ele	ctrode	Ni
3		Inner layer	Cu
4	Termination	Middle layer	Ni
(5)		Outer layer	Sn (Matt)



Storage and handling conditions

- (1) To store products at 5 to 40°C ambient temperature and 20 to 70%. related humidity conditions.
- (2) The product is recommended to be used within one year after shipment. Check solderability in case of shelf life extension is needed.

Cautions:

- a. The corrosive gas reacts on the terminal electrodes of capacitors, and results in the poor solderability. Do not store the capacitors in the ambience of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
- b. In corrosive atmosphere, solderability might be degraded, and silver migration might occur to cause low reliability.
- c. Due to the dewing by rapid humidity change, or the photochemical change of the terminal electrode by direct sunlight, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or dewing condition. To store products on the shelf and avoid exposure to moisture.

■ Recommended soldering conditions

The lead-free termination MLCCs are not only to be used on SMT against lead-free solder paste, but also suitable against lead-containing solder paste. If the optimized solder joint is requested, increasing soldering time, temperature and concentration of N_2 within oven are recommended.

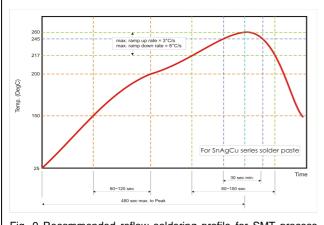


Fig. 9 Recommended reflow soldering profile for SMT process with SnAgCu series solder paste.

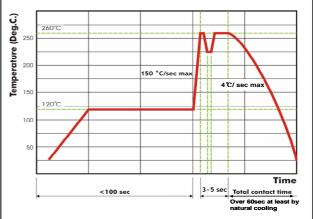


Fig. 10 Recommended wave soldering profile for SMT process with SnAgCu series solder.

